Nanoscale

Accepted Manuscript



This is an *Accepted Manuscript*, which has been through the Royal Society of Chemistry peer review process and has been accepted for publication.

Accepted Manuscripts are published online shortly after acceptance, before technical editing, formatting and proof reading. Using this free service, authors can make their results available to the community, in citable form, before we publish the edited article. We will replace this Accepted Manuscript with the edited and formatted Advance Article as soon as it is available.

You can find more information about *Accepted Manuscripts* in the **Information for Authors**.

Please note that technical editing may introduce minor changes to the text and/or graphics, which may alter content. The journal's standard <u>Terms & Conditions</u> and the <u>Ethical guidelines</u> still apply. In no event shall the Royal Society of Chemistry be held responsible for any errors or omissions in this *Accepted Manuscript* or any consequences arising from the use of any information it contains.



www.rsc.org/nanoscale

Nanoscale

Cite this: DOI: 10.1039/c0xx00000x

www.rsc.org/xxxxx

ARTICLE TYPE

High-performance humidity sensors from Ni(SO₄)_{0.3}(OH)_{1.4} nanobelts

Ming Zhuo¹, Yuejiao Chen¹, Tao Fu², Haonan Zhang¹, Zhi Xu², Qiuhong Li*^{a1} and Taihong Wang*^{b1}

75

Received (in XXX, XXX) Xth XXXXXXXX 20XX, Accepted Xth XXXXXXXX 20XX DOI: 10.1039/b000000x

⁵ Ni(SO₄)_{0.3}(OH)_{1.4} nanobelts were synthesized by a facile hydrothermal method. Humidity sensors based on Ni(SO₄)_{0.3}(OH)_{1.4} nanobelts were fabricated and exhibited high sensitivity and fast response. It also showed good long-term stability. The high performance could be related to the ¹⁰ high surface to volume ratio of nanobelts and the chemical composition of Ni(SO₄)_{0.3}(OH)_{1.4}.

Humidity displays an extensive influence on human comfort, industry manufacturing and packaging, medical care, meteorological forecast and so on.¹⁻⁵ There is a substantial ¹⁵ interest in the development of sensors for application in monitoring and detecting humidities in moisture-sensitive environment, such as glove boxes and clean rooms.

It has shown that nanomaterial-based devices have great potential for humidity sensors. Various methods have been ²⁰ developed.⁶⁻¹⁰ One dimensional (1D) nanomaterials offer a promising platform for high-performance sensing devices that employ favourable electronic transport. With large surface to volume ratio, they are expected to behave high performance because of more active sites available on the surface of the

²⁵ material for physical or chemical interaction.¹¹⁻¹³ Many humidity sensors based on 1D nanomaterials have been reported.¹⁴⁻¹⁸ But it is still a big challenge for the realization of sensors with high sensitivity, fast response, long-term stability, low cost and facile fabrication technique. Novel ³⁰ materials are being explored.¹⁹

Nickel hydroxide has attracted great interest as cathode material in alkaline batteries.²⁰⁻²³ Being intercalated with anions or water molecules, it will form hydroxyl-rich nickel basic salts, having a composition of $-Ni(A^{n-})_{x/n}(OH)_{2-x}$ ·yH₂O

³⁵ (where x=0.5~1, A=NO³⁻, Cl⁻, SO₄²⁻).²⁴⁻²⁵ Nanostructures of these salts have been realized. Ni(SO₄)_{0.3}(OH)_{1.4}, as a typical compound with 1D structure, has been reported by several groups, in which the synthesis methods and its electrochemical properties are investigated.²⁶⁻²⁹ However,
⁴⁰ there are few reports to explore its sensing properties. In this work, Ni(SO₄)_{0.3}(OH)_{1.4} nanobelts (NSOH NBs) with uniform morphology were synthesized on a large scale using a facile hydrothermal method. The sensors were fabricated using the NSOH NBs as sensitive material. Electrical characteristics
⁴⁵ and humidity sensing properties were investigated, which showed high sensitivity, good long-term stability and fast

response. The Ni(SO₄)_{0.3}(OH)_{1.4} nanobelts were synthesized in 25 mL de-ionized water, together with 2.0 mmol nickel acetate and 50 2.0 mmol sodium sulfate at 150 °C for 20 h. The morphology of the samples was examined by scanning electron microscope (SEM) with Hitachi-4800. Fig. 1a shows the typical SEM image which indicates the product consists of large quantity of nanobelts with the length about 10 to 20 µm. The phase 55 purity and crystal structure of the nanobelts was characterized

- by X-ray Diffraction (XRD) on a JEOL X-ray diffractomer using Cu-kα radiation at 40 kV and 250 mA, as shown in Fig. 1b. Obviously, all the diffraction peaks can correspond well to standard card of monoclinic paraotwayite (JCPDS No: 41-
- ⁶⁰ 1424). No peaks of impurities or other phases were detected. The XRD pattern of the sample after kept in air for one year is given in Fig. S1. It shows little change. Further details were carried out by transmission electron microscope (TEM) with
- JEOL JEM-3010. The TEM specimen was prepared by ⁶⁵ placing a drop of the nanobelts dispersed in ethanol on a Cu grid covered with a holey carbon film. Fig. 1c reveals the beltlike morphology, according with SEM images. A highresolution TEM (HRTEM) image is observed in Fig. 1d, which displays an obvious crystalline lattice with interplane ⁷⁰ spacing of 0.2208 nm, corresponding to the (10-6) plane of NSOH phase. The selected-area electron diffraction (SAED) pattern (Fig. S2) reveals the single crystal nature of the obtained material.



Fig. 1 (a) SEM images (b) XRD pattern of the Ni(SO₄)_{0.3}(OH)_{1.4} nanobelts. (c) TEM and (d) HRTEM images of the Ni(SO₄)_{0.3}(OH)_{1.4} nanobelts. The inset in (d) is the enlarged part of (d).

Humidity sensors based on $Ni(SO_4)_{0.3}(OH)_{1.4}$ nanobelts were fabricated by a simple drop method on interdigital gold so electrodes on ceramic substrate. The width and length of the

Nanoscale Accepted Manuscript



Fig. 2 (a, b) Real-time response of the RH sensor under different RHs. (c) Resistance of the sensor under each RH. (d) The ratio under different RH. The red line is the exponential fitting between the ratio and RH.

- interdigital electrode are about 2.8 and 3.5 mm, respectively. $_{5}$ The strip width of each finger is about 90 μ m and the distance between each strip electrode is about 70 µm. For preparation, the ceramic substrate was cleaned by diluted HCl, acetone and de-ionized water respectively. The as-synthesized NSOH NBs were mixed with ethanol by ultrasonic for 1 h. After that, a
- 10 drop of the suspension was coated on the substrate. The device was heated at 60 °C for the volatilization of ethanol. Bare Au interdigital electrodes and electrodes with sensing material are shown in the inset of Fig. S2. The sensing material formed thin film in light-green color. The 15 corresponding current-voltage (I-V) curve was obtained by an
- Agilent 4156C precision semiconductor parameters analyzer, as shown in Fig. S3. The I-V curve was measured in the air ambient.
- The humidity sensing properties were measured by using a 20 high precision sensor testing system NS-4003 series (China Zhong-Ke Micro-nano IOT Ltd). Temperatures and humidities were precisely controlled through a climate test chamber C 180-40 (Weiss-voetsch Environmental Testing instruments, Tai Cang Co., Ltd). The chamber volume is 190 L. A 25 schematic illustration of the sensor test system is shown in Fig.
- S4. The relative humidity (RH) and temperature of the atmosphere were 60% and 20 °C, respectively.

The resistance as a function of RH in aspect of time of the sensor was tested by NS-4003 series with an applied DC 30 voltage of 5 V. The resistance variation as a function of RH at

a constant temperature of 20 °C is presented in Fig. 2. Fig. 2a is the real-time resistance response between ambient air (60%)and different lower RH (15%, 20%, 25%, 30%, 35%, 40%, 50%) at 20 °C. It indicates a strong influence of humidity on 35 the resistance of the sensor which increases with decreasing RH. Under 60% RH, the resistance $(R_{60\%})$ is about 2.5×10⁶ Ω , which quickly increases and rapidly reaches $8.32 \times 10^9 \Omega$ when the sensor is put in the chamber of 15% RH. After the RH is back to 60%, the resistance abruptly decreases and then ⁴⁰ gradually returns to original $2.5 \times 10^6 \Omega$. The corresponding response time and recovery time (defined as the time required to reach 90% of the final equilibrium value) are about 3 s. In Fig. 2b, the measurement is based on dynamic switches of the sensor between ambient air (60%) and relatively higher RH. 45 After exposed to 70%, 80%, and 90% RH, the sensor displays corresponding resistance of about 7.94×10^5 , 4.88×10^5 , and $3.21 \times 10^5 \Omega$, respectively. The response and recovery time is longer than that when RH changes from 60% to lower humidities, which is obvious to observe in the latter two 50 cycles shown in Fig. 2(b). The resistance (log (Ω)) as a function of RH is given in Fig. 2c, which shows that the resistance of the film decreases monotonically with increasing RH in the test range of 15% - 90%. Obviously, the resistance of the film changes by more than four orders of magnitude 55 (from $10^5 \Omega$ to nearly $10^{10} \Omega$), showing ultra-high sensitivity compared with many metal oxide humidity sensors.^[6, 30-32] The



Fig. 3 The resistance decreases with RH at different temperatures.

70%, 80%, and 90% RH. The result is shown in Fig. 2d. S increases largely with RH. From 15% to 30%, it linearly

- s increases with slope 1. From 35% to 50%, *S* linearly increases with slope 71.7. From 60% to 90%, *S* linearly increases with slope 753. The performance of the sensor in dry air was also measured. The resistance R_{dry} is 3.14×10^{10} Ω. Its corresponding sensitivity is given in Fig. S5.
- To check its humidity sensitive characteristics of the sensor under different temperatures, resistance variations as a function of time were shown in Fig. 3. The measurements were carried out by RH changing from 15%, 20%, 25%, 30%, 40%, 50%, 60%, 70% to 80% when the temperature was
- ¹⁵ controlled to be 40, 50, 60, 70, 80, 90 °C, respectively. The sensor resistance decreases with RH, consistent with the result before. The result shows that the sensor exhibits similar properties under different temperatures.

The long-term stability is an important parameter for the ²⁰ practical applications of humidity sensor. Herein, the stability of the NSOH NBs sensor was monitored under different humidity conditions for 3 months. Fig. 4 shows the real-time resistance response of the sensor with different RHs at 20 °C after 3 months. It can be observed that the resistance just ²⁵ varies slightly less than 5% over the entire humidity region,



Fig. 4 The real-time resistance response with different RHs after 3 months.

³⁰ indicating the NSOH NBs sensor displays excellent long-term stability.

The good sensing ability of the Ni(SO₄)_{0.3}(OH)_{1.4} nanobelts sensor to humidity probably can be attributed to its structure and OH⁻, SO₄²⁻ groups of Ni(SO₄)_{0.3}(OH)_{1.4} ³⁵ nanobelts. Literatures have shown that 1D nanomaterial with high specific surface is highly advantageous for gas sensing, as it has a large exposure of surface atoms providing more active sites for the adsorption of gas sensing reaction, as it has a large exposure of surface atoms providing more active sites ⁴⁰ for the adsorption of gas molecules and hence promoting the surface reactions.^{14-15, 30}

Humidity sensing is related to water adsorption and desorption process.³³⁻³⁵ According to J. H. Anderson et al., protons could act as charge carriers during humidity sensing 45 process.³⁶ At low humidity, tips and defects of the nanomaterial present a high local charge density and a strong electrostatic field, which promotes water dissociation.³³ The dissociation provides protons and hydroxyl groups. Protons hop along the nanobelt, contributing to the conductance. 50 Water molecule layer is then physisorbed on the hydroxyl groups. At higher humidity, further physisorbed water layers are adsorbed on the first water layer. H₃O⁺ appears and serves as a charge carrier.³⁷⁻⁴⁰ In our work, OH⁻ groups exists initially in NSOH NBs. It could be effective sites to adsorb 55 water molecules, which is believed to be a great contribution for NSOH NBs to exhibit a better performance. Fig. S7a shows nanobelt without the chemical composition OH-. The OH⁻ shown in Fig. S5a is formed by dissociation of water and then absorbed on the surface of the nanobelts. While the 60 nanobelt contains OH as shown in Fig. S7b, the water dissociation also happens. In the same time, it has more active sites to adsorb water molecules, thus more protons take part in the conduction, leading to the decrease of the resistance. When humidity gets even higher, more water molecules layers 65 are adsorbed on the humidity sensor. Liquid water layers form on the surface of the nanobelt. In experimental section, S increases with humidity, with different slope in three RH regions. The response/recovery time also increase when RH changes from 60% to higher humidites. These experimental 70 results could be related to the three humidity sensing process.

In conclusion, we reported the growth of single crystal NSOH NBs by a hydrothermal method. Sensitive humidity sensor was then fabricated with the nanobelts coated on ceramic substrate with Au interdigital electrodes. By 75 measuring resistance of the device at different humidities and temperatures, the humidity sensing properties were studied. Resistance of the humidity sensor decreased monotonically with increasing RH. At 20 °C, the resistance changes of more than four orders of magnitude was observed when NSOH NBs 80 device was measured in 15% and 90% RH, respectively. The real-time response of the device show its rapid response and recovery time less than 3 s. Three months later, the measurement results show little variation. High sensitivity, fast response, long-term stability of the nanobelt sensor is 85 potentially useful for humidity sensing. The high performance of the humidity sensor can to be contributed to its 1D morphology and its chemical composition.

Acknowledgements

This study was supported by the National Natural Science Foundation of China (Grant No. 21003041, 61376073), Hunan Provincial Natural Science Foundation of China (Grant No.

5 11JJ7004), and the Specialized Research Fund for the Doctoral Program of Higher Education of China (20120161110016)

Notes and references

1. College of electrical and information engineerin. Hunan University. 10 Fax: +86 731 88664019; Tel: +86 731 88664019;

- 2.Key Laboratory for Micro-Nano Optoelectronic Devices of Ministry of Education Hunan University. State Key Laboratory for Chemo/Biosensing and Chemometrics Hunan University. Fax: +86 731 88822332; Tel: +86 731 88822332;
- 15 ^aE-mail: liqiuhong2004@hotmail.com ^bE-mail: thwang@iphy.ac.cn † Electronic Supplementary Information (ESI) available: [details of any supplementary information available should be included here]. See DOI: 10.1039/b000000x/

‡ Footnotes should appear here. These might include comments relevant

- 20 to but not central to the matter under discussion, limited experimental and spectral data, and crystallographic data.
- 1 G. Delapierre, H. Grange, B. Chambaz, L. Destaunes, Sens. Actuators B 1983 (4) $97 \sim 104$
- G. Wang, Q. Wang, W. Lu and J. H. Li, J. Phys. Chem. B 2006 (110) 22029~22034. 25 2
- 3 Q. Kuang, C. S. Lao, Z. L. Wang, Z. X. Xie, L. S. Zheng, J. Am. Chem. Soc. 2007 (129) 6070-6071. 4 H. B. Hu, Q. W. Chen, K. C, J. Tang J. Mater. Chem., 2012 (22) 1021~1027
- 30 5 Y. Zhu, J. C. Chen, H. M Li, Y. H. Zhu, J. Q. Xu Sens. Actuators B 2014 (193) 320~325
- S. P. Chang, S. J. Chang, C. Y. Lu, M. J. Li, C. L. Hsu, Y. Z. Chiou, T. J. Hsueh, I. 6. C. Chen, Superlattices and Microstructures 2010 (47) 772-778
- 7 Y. S. Zhang, K. Yu, S. X. Ouyang, L. Q. Luo, H. M. Hu, Q. X. Zhang, Z. Q. Zhu, physica B 2005 (368) 94-99. 35
- 8 J. Xu, W. X. Zhang, Z. H. Yang, S. X. Ding, C. Y. Zeng, L. L. Chen, Q. Wang, S. H. Yang, Adv. Funct. Mater. 2009 (19) 1759-1766. F. S. Tsai, S. J. Wang Sens. Actuators B 2014 (193) 280~287
- 10. J. D. Li, T. Fu, Y. J. Chen, B. K. Guan, M. Zhuo, T. Yang, Z. Xu, Q. L. Li, M. Zhang CrystEngComm 2014, accepted DOI:10.1039/C3CE42172D 40
- 11 Y. Cui, Q. Q. Wei, H. K. Park, C. M. Lieber, Science 2001 (293) 1289-1292.
- 12 A. Kolmakov, D. O. Klenov , Y. Lilach, S. Stemmer, and M. Moskovits, Nano. Lett. 2005 5667-673
- 13 Y. J. Chen, L. Nie, X. Y. Xue, Y. G. Wang, T. H. Wang, appl. Phys. Lett. 2006 (88) 083105 45
- 14 C. H. Kim, Y. Myung, Y. J. Cho, H. S. Kim, S. H. Park, J. Park, J. Phys. Chem. C 2009 (113) 7085-7090
- 15. W. Kim, A. Javey, O. Vermesh, Q. Wang, Y. L, H. J. D, nanolett. 2003 (3) 193-198
- A. Erol, S. Okur, N.Ya' gmurcukardes, M.C. Arıkan, Sens. Actuators B 2011 (152) 50 16 115~120
- Y. Lu, Z. Y. Wang, S. Yuan, L. Y. Shi, Y. Zhao, W.Deng RSC Adv. 2013 (3) 17. 11707-11714
- 18 U. Mogera, A. A. Sagade, S. J. George, G. U. Kulkarni Sci. Rep.2014 (4) 4103 L. L. Gu, K. B Zheng, Y. Zhou, J. Li, X. L. Mo, G. R. Patzkeb, G. R. Chen, Sens. 55 19. Actuators B 2011 1591-7
- 20. M. H. Cao, X. Y. He, J. Chen, C. W. Hu crystal growth design 2007 (7) 170~174 D. E. Reisner, A. J. Salkind, P. R. Strutt, T. D. Xiao Journal of power sources 21
- 1997 (65) 231~233 60 22. M. B. J. G. Freitas Journal of Power Sources 2001 (93) 163~173
- 23 M. A. Kiani, M. F. Mousavi, S. Ghasemi Journal of Power Sources 2010 (195) 5794~5800
- 24. W. Wen, J. M. Wu, L. L. Lai, G. P. Ling, M. H. Cao, CrystEngComm. 2012 (14) 6565~6572
- 65 25. D. G. Yang, P. C. L, Y. Gao, H. Wu, Y. Cao, Q. Z. Xiao, H. M. Li, J. Mater. Chem. 2012 (22) 7224
- 26. L. Li, J. Liang, M. Luo, J. Z. Fang, Powder Technology 2012 (226) 143~146
- 27 H. Zhou, B. L. Lv, D. Wu, Y. H. Sun, J Alloy. And Comp. 2012 (540) 127~132 28 Z. Y. Jia IEEE 2011 673~677
- K. Zhang, J. B. Wang, X. L. Lu, L. Y. Li, Y. W. Tang, Z. Y. J J. Phys. Chem. C. 70 29 2009 (113) 142~147
- 30 H. T. Hsueha, T.J. Hsueh, S. J. Chang, F. Y. Hung, T. Y. Tsai, W. Y. Weng, C. L. Hsu, B. T. Dai, Sens. Actuators B 2011 (156) 906-911
- 31. Y. S. Zhang, K. Yu, D. S. Jiang, Z. Q. Zhu, H. R. Geng, L. Q. Luo, Applied surface science 2005 (242) 212~217 75
- 32. S. Thakur, P. Patil Sens. Actuators B 2014 (194) 260~268
- X. Q. Fu, C. Wang, H. C. Yu, Y. G. Wang, T. H. Wang, Nanotechnology 2007 (18) 33.

145503

- 34 M. Trigo-López, A. Muñoz, S. Ibeas, F. C. García, F. Serna, J. M. García Sens. 80 Actuators B 2014 (191) 233~238 35.
 - G. Rubasinghege, V. H. Grassian Chem. Commun. 2013 (49) 3071~3094
 - C. L. Cao, C. G. Hu, L. Fang, S. X.Wang, Y. S. Tian, C. Y. Pan, Journal of 36. Nanomaterials 2011 707303
 - 37. J. H. Andersonl, G. A. Parks, The Journal of Physical Chemistry 1968 (72) 3662~3668 M. Zhuo, Y. Chen, J. Sun, H. Zhang, D. Guo, H. Zhang, Q. H. Li, T. H. Wang, Q.
 - Wan Sens. Actuators B 2013 (186) 78~83. Y. P. Zhang, J. Wu, Y. Zhang, W. B. Guo, S. P. Ruan Sens. Actuators B 2014 (14) 39.
- 4303~4307 90 40.
 - W. Van Gaens, A. Bogaerts J. Phys. D: Appl. Phys. 2014 (47) 079502 (3pp)

Vanoscale Accepted Manuscript

4 | Journal Name, [year], [vol], 00-00 85 38.